General Purpose Transistors

PNP Silicon

This transistor is designed for general purpose amplifier applications. It is housed in the SOT-416/SC-75 package which is designed for low power surface mount applications.

Features

- NSVM Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS $(T_A = 25^{\circ}C)$

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V _{CEO}	-40	Vdc
Collector-Base Voltage	V _{CBO}	-40	Vdc
Emitter-Base Voltage	V _{EBO}	-5.0	Vdc
Collector Current – Continuous	Ic	-200	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation, FR-4 Board (Note 1) @T _A = 25°C Derated above 25°C	P _D	200 1.6	mW mW/°C
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{\theta JA}$	600	°C/W
Total Device Dissipation, FR-4 Board (Note 2) @T _A = 25°C Derated above 25°C	P _D	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{\theta JA}$	400	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	-65 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

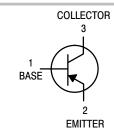
- 1. FR-4 @ Minimum Pad
- 2. FR-4 @ 1.0 × 1.0 Inch Pad



ON Semiconductor®

www.onsemi.com

GENERAL PURPOSE AMPLIFIER TRANSISTORS SURFACE MOUNT





CASE 463 SOT-416/SC-75 STYLE 1

MARKING DIAGRAM



2A = Device Code M = Date Code* • = Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping _†
MMBT3906TT1G	SOT-416 (Pb-Free)	3000 / Tape & Reel
NSVMMBT3906TT1G	SOT-416 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

	Characteristic	Symbol	Min	Max	Unit	
OFF CHARACTERIST	TICS	<u>.</u>				
Collector – Emitter Brea (I _C = –1.0 mAdc, I _E	akdown Voltage (Note 3) = 0)	V _(BR) CEO	-40	-	Vdc	
Collector – Base Break $(I_C = -10 \mu Adc, I_E = -10 \mu Ad$	V _(BR) CBO	-40	-	Vdc		
Emitter – Base Breakdo ($I_E = -10 \mu Adc, I_C =$	V _{(BR)EBO}	-5.0	-	Vdc		
Base Cutoff Current (V _{CE} = -30 Vdc, V _I	I _{BL}	_	-50	nAdd		
Collector Cutoff Currer (V _{CE} = -30 Vdc, V _I	I _{CEX}	_	-50	nAdd		
ON CHARACTERISTI	CS (Note 3)	•	•	•	•	
DC Current Gain	h _{FE}	60 80 100 60 30	- 300 - -	_		
Collector – Emitter Sati ($I_C = -10 \text{ mAdc}, I_B$ ($I_C = -50 \text{ mAdc}, I_B$	V _{CE(sat)}	_ _	-0.25 -0.4	Vdc		
Base – Emitter Saturati ($I_C = -10$ mAdc, I_B ($I_C = -50$ mAdc, I_B	V _{BE(sat)}	-0.65 -	-0.85 -0.95	Vdc		
SMALL-SIGNAL CHA	ARACTERISTICS					
Current – Gain – Bando ($I_C = -10 \text{ mAdc}, V_C$	f _⊤	250	_	MHz		
Output Capacitance (V _{CB} = -5.0 Vdc, I _E	= 0, f = 1.0 MHz)	C _{obo}	-	4.5	pF	
Input Capacitance1 (V _{EB} = -0.5 Vdc, I _C	C _{ibo}	_	10.0	pF		
Input Impedance (V _{CE} = -10 Vdc, I _C	h _{ie}	2.0	12	kΩ		
Voltage Feedback Rat (V _{CE} = -10 Vdc, I _C	h _{re}	0.1	10	X 10 ⁻		
Small – Signal Current (V _{CE} = –10 Vdc, I _C	h _{fe}	100	400	-		
Output Admittance (V _{CE} = -10 Vdc, I _C	h _{oe}	3.0	60	μmho		
Noise Figure (V _{CE} = -5.0 Vdc, I _C	NF	-	4.0	dB		
SWITCHING CHARAC	CTERISTICS					
Delay Time	$(V_{CC} = -3.0 \text{ Vdc}, V_{BE} = 0.5 \text{ Vdc})$	t _d	_	35		
Rise Time	$(I_C = -10 \text{ mAdc}, I_{B1} = -1.0 \text{ mAdc})$	t _r	-	35 ns		
Storage Time	$(V_{CC} = -3.0 \text{ Vdc}, I_C = -10 \text{ mAdc})$	t _s	-	225	ns	
Fall Time	$(I_{B1} = I_{B2} = -1.0 \text{ mAdc})$	t _f	-	75		

^{3.} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.

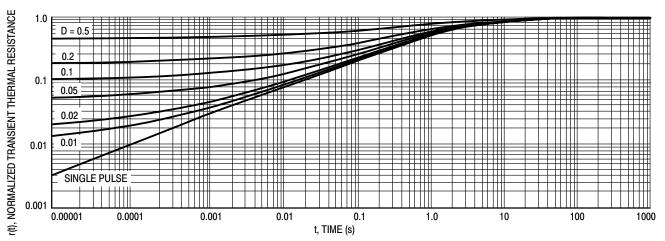
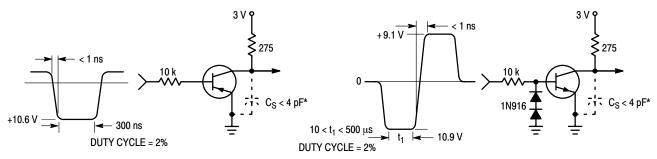


Figure 1. Normalized Thermal Response



* Total shunt capacitance of test jig and connectors

Figure 2. Delay and Rise Time Equivalent Test Circuit

Figure 3. Storage and Fall Time Equivalent Test Circuit

TYPICAL TRANSIENT CHARACTERISTICS

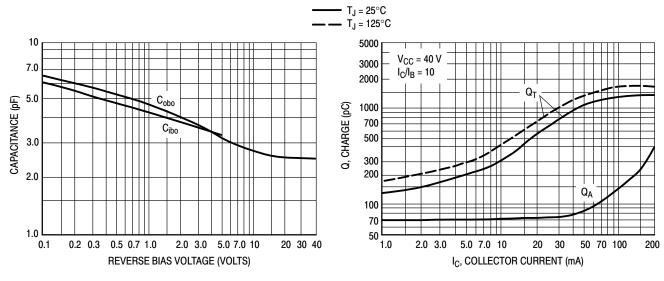


Figure 4. Capacitance

Figure 5. Charge Data

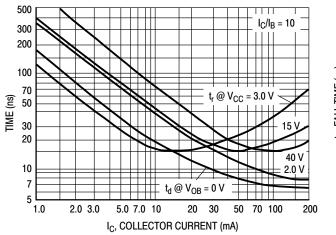


Figure 6. Turn-On Time

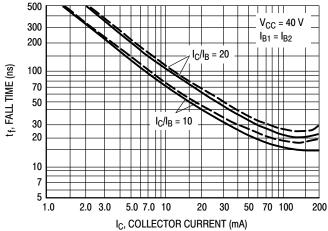
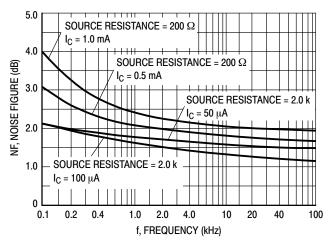


Figure 7. Fall Time

TYPICAL AUDIO SMALL-SIGNAL CHARACTERISTICS NOISE FIGURE VARIATIONS

 $(V_{CE} = -5.0 \text{ Vdc}, T_A = 25^{\circ}\text{C}, Bandwidth = 1.0 \text{ Hz})$



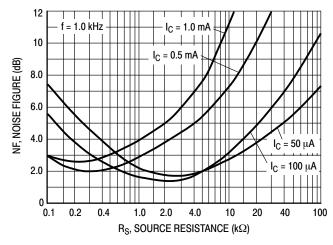
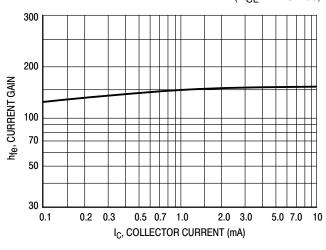


Figure 8.

Figure 9.

h PARAMETERS

 $(V_{CE} = -10 \text{ Vdc}, f = 1.0 \text{ kHz}, T_A = 25^{\circ}\text{C})$



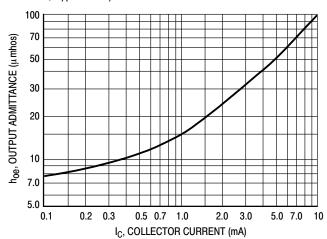
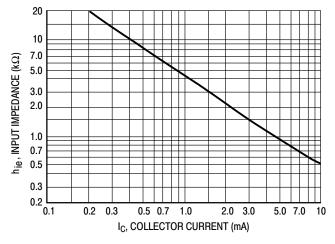


Figure 10. Current Gain

Figure 11. Output Admittance



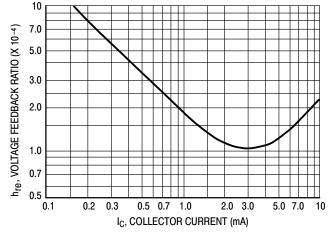


Figure 12. Input Impedance

Figure 13. Voltage Feedback Ratio

STATIC CHARACTERISTICS

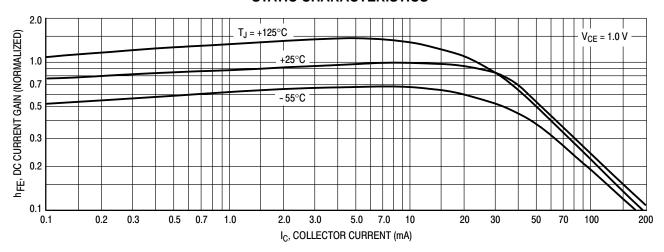


Figure 14. DC Current Gain

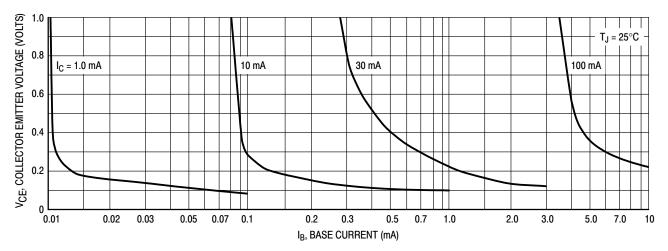


Figure 15. Collector Saturation Region

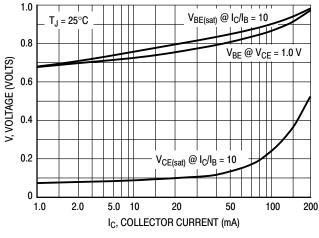


Figure 16. "ON" Voltages

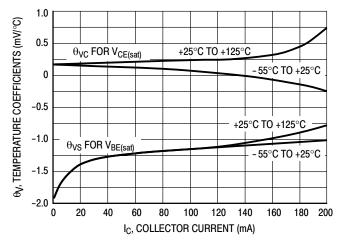


Figure 17. Temperature Coefficients

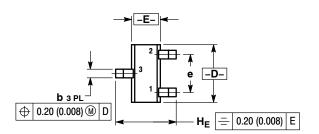
MECHANICAL CASE OUTLINE

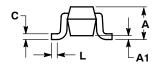




SC-75/SOT-416 CASE 463-01 **ISSUE G**

DATE 07 AUG 2015





STYLE 1: PIN 1. BASE 2. EMITTER

3. COLLECTOR

STYLE 4: PIN 1. CATHODE 2. CATHODE 3. ANODE STYLE 5: PIN 1. GATE 2. SOURCE 3. DRAIN

STYLE 2: PIN 1. ANODE 2. N/C 3. CATHODE

STYLE 3: PIN 1. ANODE 2. ANODE 3. CATHODE

NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETER.

-		MILLIMETERS			INCHES		
L	DIM	MIN	NOM	MAX	MIN	NOM	MAX
	Α	0.70	0.80	0.90	0.027	0.031	0.035
L	A1	0.00	0.05	0.10	0.000	0.002	0.004
	b	0.15	0.20	0.30	0.006	0.008	0.012
	С	0.10	0.15	0.25	0.004	0.006	0.010
	D	1.55	1.60	1.65	0.061	0.063	0.065
	Е	0.70	0.80	0.90	0.027	0.031	0.035
	е	1.00 BSC				0.04 BSC)
	L	0.10	0.15	0.20	0.004	0.006	0.008
	HE	1.50	1.60	1.70	0.060	0.063	0.067

GENERIC MARKING DIAGRAM*

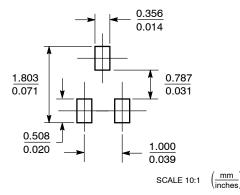


XX= Specific Device Code

Μ = Date Code

= Pb-Free Package

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

DOCUMENT NUMBER:	98ASB15184C	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.		
DESCRIPTION:	SC-75/SOT-416		PAGE 1 OF 1	

ON Semiconductor and (III) are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

^{*}This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. Onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any EDA class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer pu

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT: Email Requests to: orderlit@onsemi.com

onsemi Website: www.onsemi.com

TECHNICAL SUPPORT North American Technical Support: Voice Mail: 1 800-282-9855 Toll Free USA/Canada Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support:

Phone: 00421 33 790 2910

For additional information, please contact your local Sales Representative